



PJV1717

20V P-Channel Enhancement Mode MOSFET

Voltage

-20 V

Current

420mA

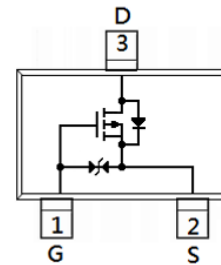
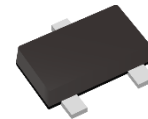
Features

- Advanced Trench Process Technology
- ESD Protected
- Specially Designed for Switch Load, PWM Application, etc
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

- Case : SOT-723 Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 0.0001 ounce, 0.0013 gram

SOT-723



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS
Drain-Source Voltage		V _{DS}	-20	V
Gate-Source Voltage		V _{GS}	±8	
Continuous Drain Current ^(Note 4)		I _D	420	mA
Pulsed Drain Current ^(Note 1)		I _{DM}	1000	
Power Dissipation	T _A =25°C	P _D	150	mW
	Derate above 25°C		1.2	mW/°C
Operating Junction and Storage Temperature Range		T _J , T _{STG}	-55~150	°C
Typical Thermal Resistance		R _{θJA}	833	°C/W
- Junction to Ambient ^(Note 5)				



PJV1717

Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V, I _D =-250uA	-20	-	-	V
Gate Threshold Voltage	V _{GS(th)}	V _{DS} =V _{GS} , I _D =-250uA	-0.3	-0.64	-1.0	
Drain-Source On-State Resistance	R _{DSON}	V _{GS} =-4.5V, I _D =-300mA	-	420	600	mΩ
		V _{GS} =-2.5V, I _D =-200mA	-	540	850	
		V _{GS} =-1.8V, I _D =-100mA	-	685	1200	
		V _{GS} =-1.5V, I _D =-50mA	-	855	1600	
		V _{GS} =-1.2V, I _D =-20mA	-	1540	3000	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =-20V, V _{GS} =0V	-	-	-1	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} =±8V, V _{DS} =0V	-	-	±10	
Dynamic ^(Note 6)						
Total Gate Charge	Q _g	V _{DS} =-16V, I _D =-300mA, V _{GS} =-4.5V ^(Note 2,3)	-	1.2	-	nC
Gate-Source Charge	Q _{gs}		-	0.1	-	
Gate-Drain Charge	Q _{gd}		-	0.2	-	
Input Capacitance	C _{iss}	V _{DS} =-10V, V _{GS} =0V, f=1MHZ	-	57.5	-	pF
Output Capacitance	C _{oss}		-	14.2	-	
Reverse Transfer Capacitance	C _{rss}		-	0.18	-	
Gate resistance	R _g	f=1.0MHZ	-	3.7	-	Ω
Turn-On Delay Time	t _{d(on)}	V _{DS} =-16V, I _D =-300mA, V _{GS} =-4.5V, R _G =3.3Ω ^(Note 2,3)	-	6	-	ns
Turn-On Rise Time	t _r		-	23	-	
Turn-Off Delay Time	t _{d(off)}		-	1576	-	
Turn-Off Fall Time	t _f		-	752	-	
Drain-Source Diode						
Diode Forward Current	I _S	---	-	-	-180	mA
Diode Forward Voltage	V _{SD}	I _S =-300mA, V _{GS} =0V	-	-0.85	-1	V

Notes :

- 1.Pulse width<300us, Duty cycle<2%.
- 2.Essentially independent of operating temperature typical characteristics.
- 3.Repetitive rating, pulse width limited by junction temperature T_J(MAX)=150°C.Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4.The maximum current rating is package limited.
- 5.R_{θJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper.
- 6.Guaranteed by design, not subject to production testing.



PJV1717

TYPICAL CHARACTERISTIC CURVES

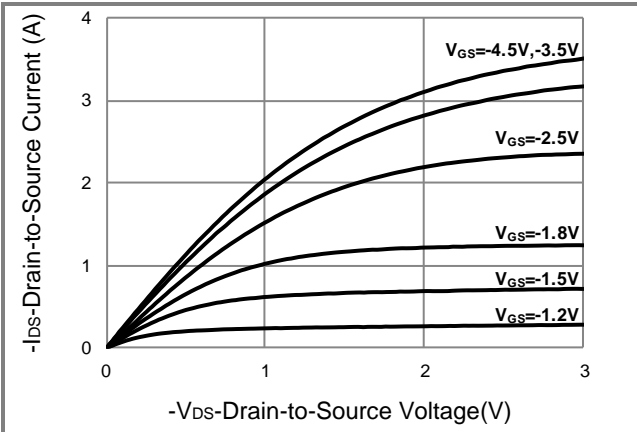


Fig.1 Output Characteristics

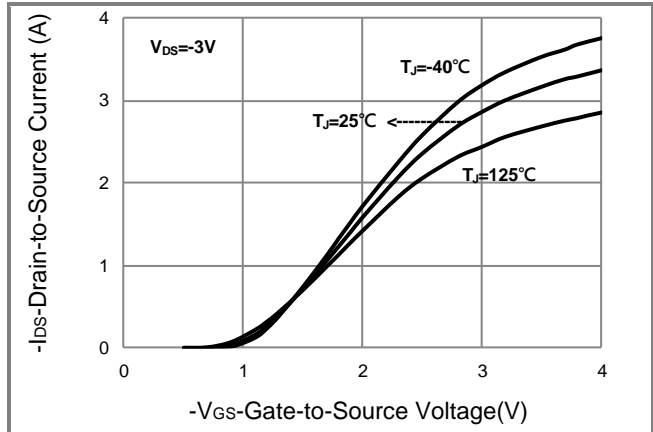


Fig.2 Transfer Characteristics

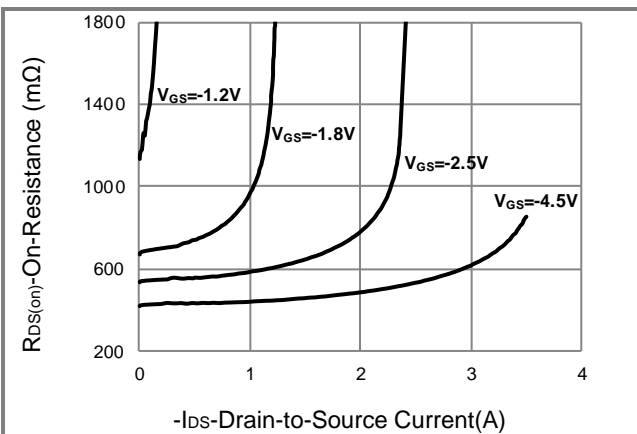


Fig.3 On-Resistance vs. Drain Current

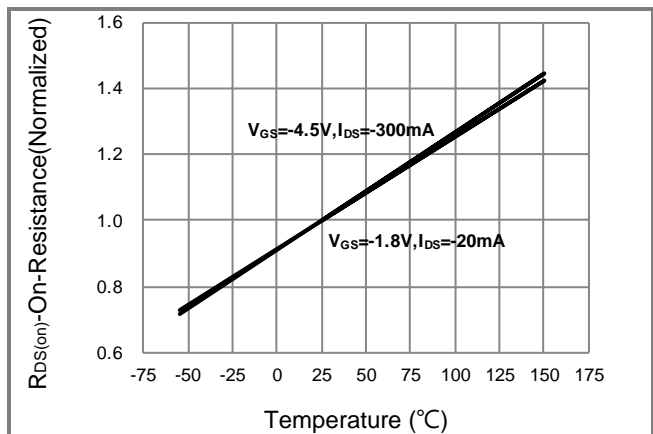


Fig.4 On-Resistance vs. Junction temperature

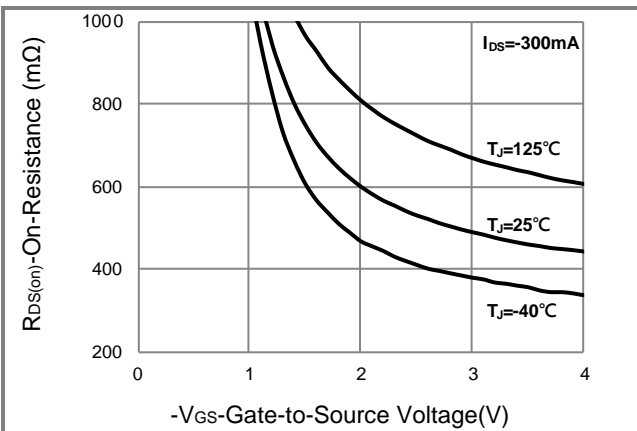


Fig.5 On-Resistance Variation with V_{GS}

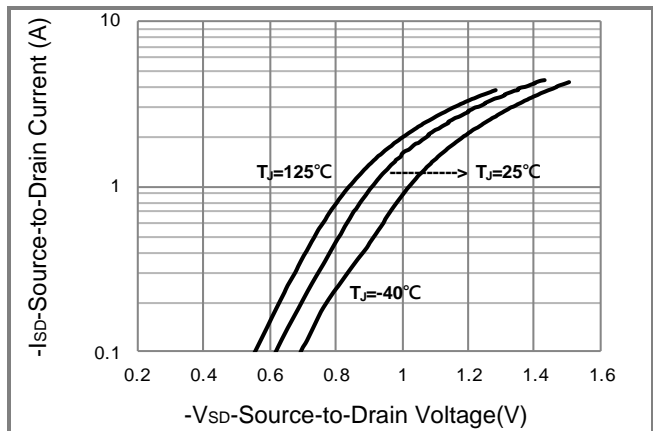


Fig.6 Source-Drain Diode Forward Voltage



PJV1717

TYPICAL CHARACTERISTIC CURVES

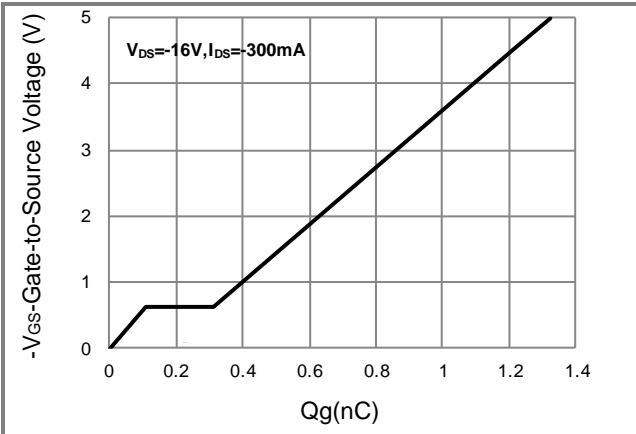


Fig.7 Gate-Charge Characteristics

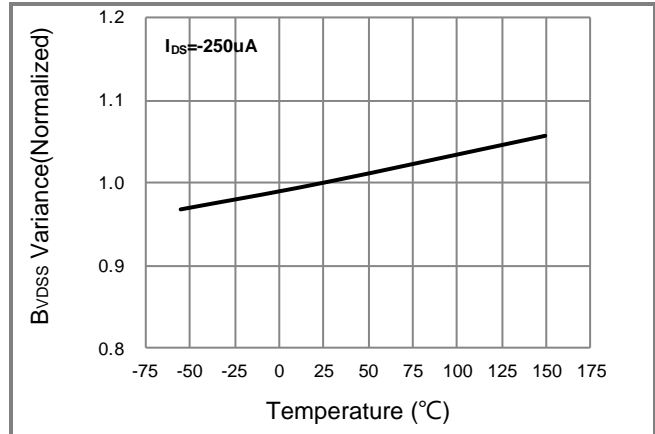


Fig.8 Breakdown Voltage Variation vs. Temperature

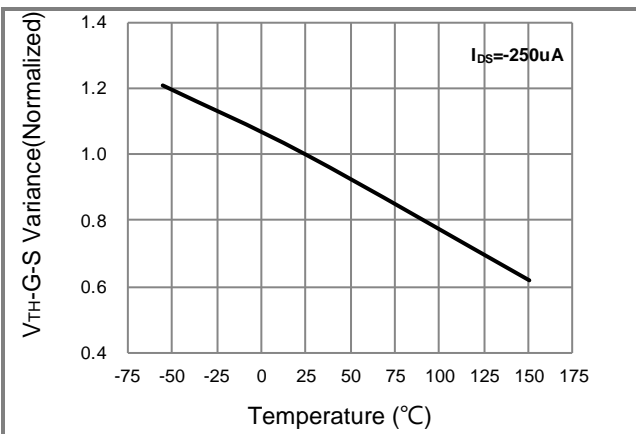


Fig.9 Threshold Voltage Variation with Temperature

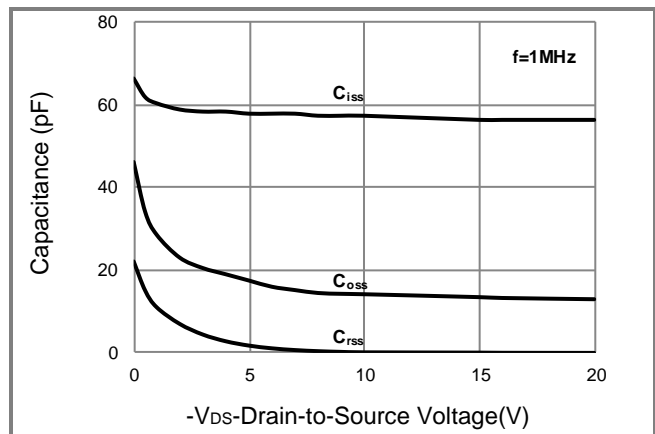


Fig.10 Capacitance vs. Drain-Source Voltage

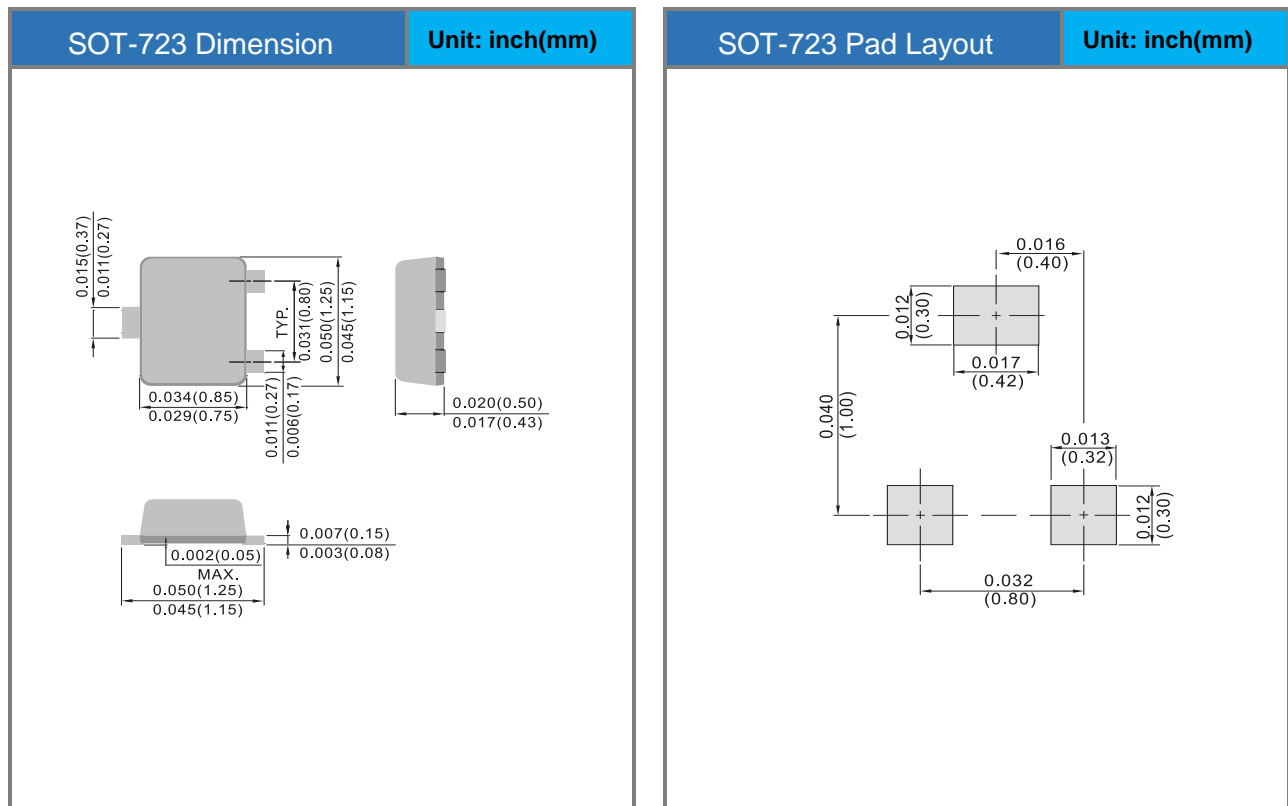


PJV1717

Part No. Packing Code Version

Part No. Packing Code	Package Type	Packing Type	Marking	Version
PJV1717_R1_00301	SOT-723	8K pcs / 7" reel	17	Halogen free RoHS compliant

Packaging Information & Mounting Pad Layout





PJV1717

Disclaimer

- Reproducing and modifying information of the document is prohibited without permission from Panjit International Inc..
- Panjit International Inc. reserves the rights to make changes of the content herein the document anytime without notification. Please refer to our website for the latest document.
- Panjit International Inc. disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially occurred.
- Panjit International Inc. does not assume any and all implied warranties, including warranties of fitness for particular purpose, non-infringement and merchantability.
- Applications shown on the herein document are examples of standard use and operation. Customers are responsible in comprehending the suitable use in particular applications. Panjit International Inc. makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.
- The products shown herein are not designed and authorized for equipments requiring high level of reliability or relating to human life and for any applications concerning life-saving or life-sustaining, such as medical instruments, transportation equipment, aerospace machinery et cetera. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify Panjit International Inc. for any damages resulting from such improper use or sale.
- Since Panjit uses lot number as the tracking base, please provide the lot number for tracking when complaining.